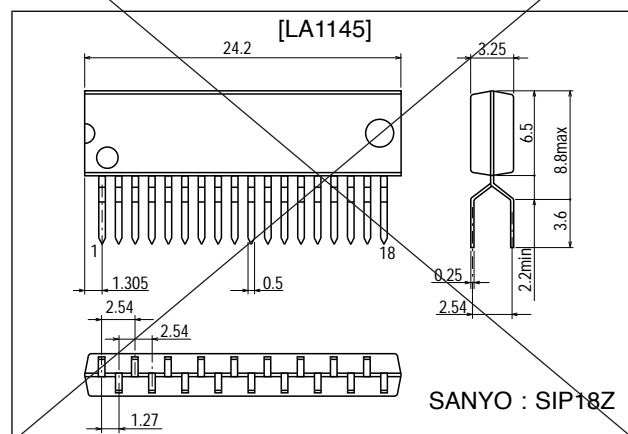


SANYO**FM IF System (Quadrature Detector) for Car Radio****Features**

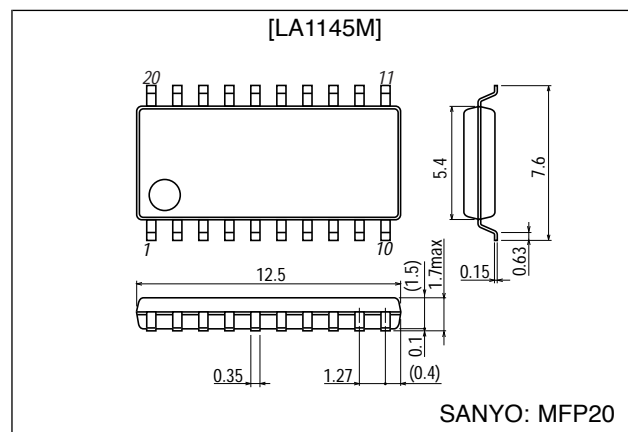
1. On-chip IF count buffer circuit and microprocessor-controlled switch circuit for ETR.
2. Compared to the LA1140, the LA1145, 1145M offer:
 - ① Improved signal meter output linearity;
 - ② Improved band mute temperature stability;
 - ③ Improved S/N ratio;
 - ④ Improved sound quality at weak signal input when noise is present, and;
 - ⑤ Improved AMR characteristics during weak signal input.
3. Reduced parts' count simplifies design:
 - ① On-chip IF count buffer circuit;
 - ② On-chip SD circuit — sensitivity can be set independently of soft mute characteristics, and;
 - ③ Variable S-meter gradient — three pin S-meter output (pins 5, 16 and 17) facilitates independent control of SNC and HCC.

Package Dimensions

unit : mm

3115-SIP18Z

unit : mm

3036C-MFP20

■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

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SANYO Electric Co., Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

LA1145, 1145M

Specifications

[LA1145]

Maximum Ratings at Ta = 25 °C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|---------------------|------------|-------------|------|
| Maximum supply voltage | V _{CC} max | Pin 12 | 14 | V |
| Maximum supply current | I _{CC} max | Pin 12 | 45 | mA |
| Allowable power dissipation | Pd max | Ta = 65 °C | 630 | mW |
| | | Ta = 70 °C | 590 | mW |
| Operating temperature | Topr | | -20 to +70 | °C |
| Storage temperature | Tstg | | -40 to +150 | °C |

Operating Conditions at Ta = 25 °C

| Parameter | Symbol | Conditions | Ratings | Unit |
|----------------------------|--------------------|------------|-----------|------|
| Recommended supply voltage | V _{CC} | | 8 | V |
| Operating voltage range | V _{CC} op | | 7.5 to 14 | V |

Operating Characteristics at Ta = 25 °C, V_{CC} = 8 V, f_{in} = 10.7 MHz

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|-----------------------------------|------------------------|---|-------|-----|-------|-------|
| Quiescent current | I _{CCO} | V _{IN} = 0 dBμ | 18 | 26 | 36 | mA |
| Current drain | I _{CC} | V _{IN} = 100 dBμ | 20 | 29 | 36 | mA |
| Demodulation output | V _O | V _{IN} = 100 dBμ, 400 Hz tone, 100% | 300 | 400 | 520 | mVrms |
| Total harmonic distortion | THD | V _{IN} = 100 dBμ, 400 Hz tone, 100%, single tuning coil | | 0.3 | 0.8 | % |
| Signal-to-noise ratio | S/N | V _{IN} = 100 dBμ, 400 Hz tone, 100% | 79 | 85 | | dB |
| Input limiting voltage | V _{IN} (lim) | 400 Hz tone, 100%, soft mute ON | 34 | 40 | 46 | dBμ |
| Muting sensitivity | V _{IN} (mute) | V ₁₅ = 2 V | 30 | 36 | 42 | dBμ |
| Muting bandwidth | BW(mute) | V _{IN} = 100 dBμ, V ₁₈ ≤ 0.3 V | 140 | 190 | 280 | kHz |
| Muting attenuation | mute(1) | V _{IN} = 100 dBμ, V ₁₅ = 2 V, 400 Hz tone, 100% | 10 | 15 | 20 | dB |
| | mute(2) | V _{IN} = 100 dBμ, V ₁₅ = 4 V, 400Hz tone, 100% | 25 | 29 | 33 | dB |
| Signal strength indication output | V ₁₆₋₀ | V _{IN} = 0 dBμ, R _A = 10 kΩ, pin 16 | 0 | 0.1 | 0.4 | V |
| | V ₁₆₋₅₀ | V _{IN} = 50 dBμ, R _A = 10 kΩ, pin 16 | 1.4 | 2.3 | 3.2 | V |
| | V ₁₆₋₇₀ | V _{IN} = 70 dBμ, R _A = 10 kΩ, pin 16 | 2.5 | 4.5 | 5.5 | V |
| | V ₁₆₋₁₀₀ | V _{IN} = 100 dBμ, R _A = 10 kΩ, pin 16 | 5.0 | 5.5 | 6.0 | V |
| Muting drive output | V ₁₅₋₀ | V _{IN} = 0 dBμ, pin 15 | 4.0 | 4.8 | 5.5 | V |
| | V ₁₅₋₁₀₀ | V _{IN} = 100 dBμ, pin 15 | 0 | 0 | 0.3 | dB |
| AM rejection ratio | AMR | V _{IN} = 100 dBμ, 1 kHz tone, 30% AM | 57 | 70 | | dB |
| Offset voltage | V ₇₋₁₁ | V _{IN} = 0 dBμ, pins 7 to 11 | -0.25 | 0 | +0.25 | V |
| | V ₈₋₁₁ | V _{IN} = 0 dBμ, pin 8 to 11 | -0.5 | 0 | +0.5 | V |
| SD sensitivity | V _{SD} | Pin 18 | 50 | 58 | 66 | dBμ |
| IF count output level | V _{IN} (IF) | V _{IN} = 100 dBμ, pin 13, C _L = 10 pF | 110 | 180 | 280 | mVrms |

[LA1145M]

Maximum Ratings at Ta = 25 °C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|---------------------|---|-------------|------|
| Maximum supply voltage | V _{CC} max | Pin 13 | 14 | V |
| Maximum supply current | I _{CC} max | Pin 13 | 45 | mA |
| Allowable power dissipation | Pd max | Ta = 70 °C, mounted on PC board, independent IC | 630 | mW |
| | | Ta = 25 °C, mounted on PC board, Independent IC | 630 | mW |
| Operating temperature | Topr | | -20 to +70 | °C |
| Storage temperature | Tstg | | -40 to +125 | °C |

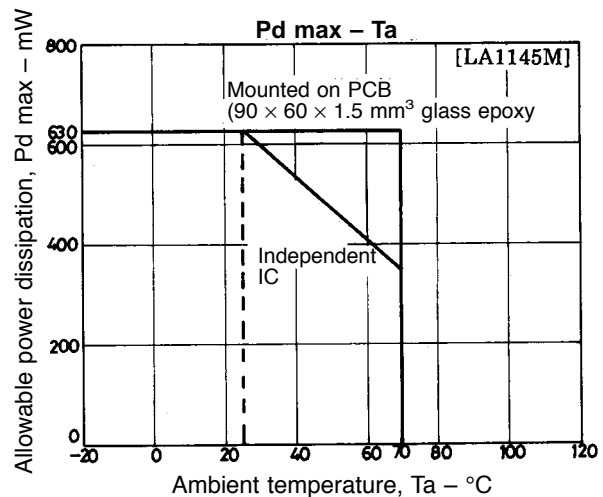
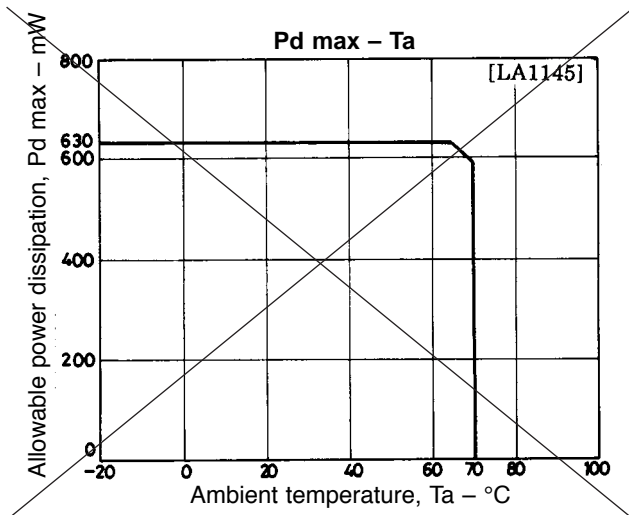
LA1145, 1145M

Operating Conditions at Ta = 25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|----------------------------|--------------------|------------|-----------|------|
| Recommended supply voltage | V _{CC} | | 8 | V |
| Operating voltage range | V _{CC op} | | 7.5 to 14 | V |

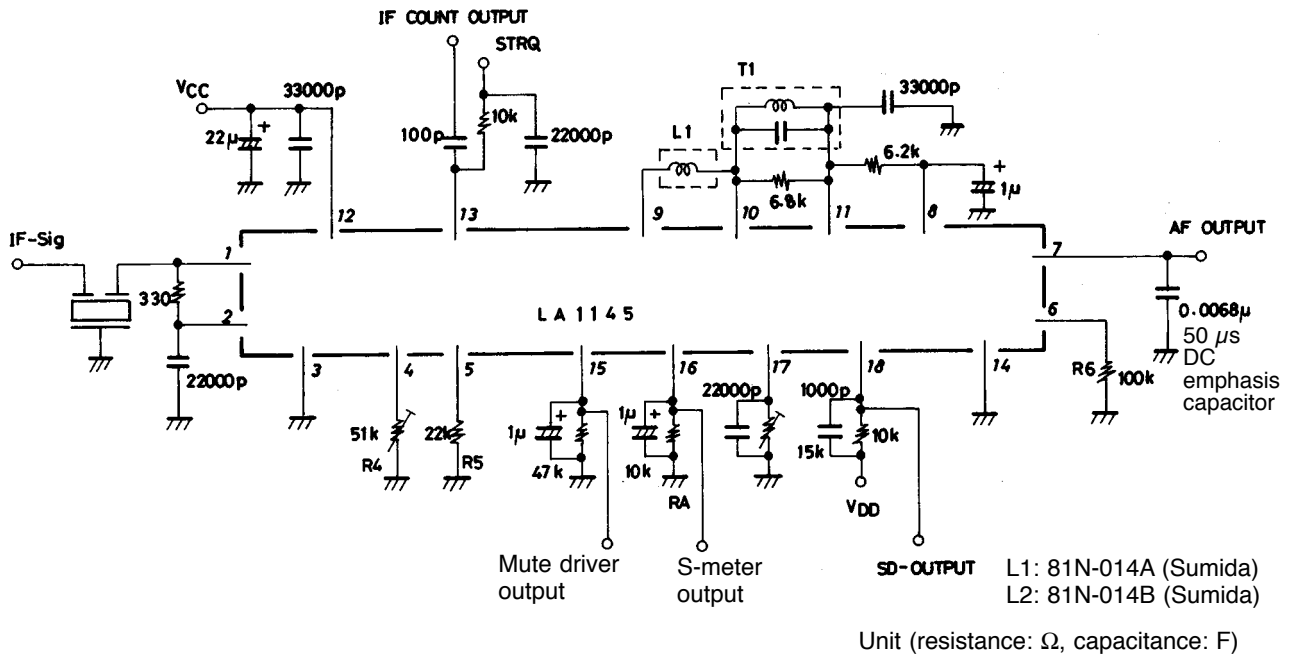
Operating Characteristics at Ta = 25 °C, V_{CC} = 8 V, f_{in} = 10.7 MHz

| Parameter | Symbol | Conditions | min | typ | max | Unit |
|-----------------------------------|------------------------|---|-------|-----|-------|-------|
| Quiescent current | I _{CCO} | V _{IN} = 0 dBμ | 18 | 26 | 36 | mA |
| Current drain | I _{CC} | V _{IN} = 100 dBμ | 20 | 29 | 40 | mA |
| Demodulation output | V _O | V _{IN} = 100 dBμ, 400 Hz tone, 100% | 300 | 400 | 520 | mVrms |
| Total harmonic distortion | THD | V _{IN} = 100 dBμ, 400 Hz tone, 100%, single tuning coil | | 0.3 | 0.8 | % |
| Signal-to-noise ratio | S/N | V _{IN} = 100 dBμ, 400 Hz tone, 100% | 79 | 85 | | dB |
| Input limiting voltage | V _{IN (lim)} | 400 Hz tone, 100%, soft mute ON | 34 | 40 | 46 | dBμ |
| Muting sensitivity | V _{IN (mute)} | V ₁₆ = 2 V | 30 | 36 | 42 | dBμ |
| Muting bandwidth | BW (mute) | V _{IN} = 100 dBμ, V ₁₉ ≤ 0.3 V | 140 | 190 | 280 | kHz |
| Muting attenuation | mute (1) | V _{IN} = 100 dBμ, V ₁₆ = 2 V, 400 Hz tone, 100% | 10 | 15 | 20 | dB |
| | mute (2) | V _{IN} = 100 dBμ, V ₁₆ = 4 V, 400 Hz tone, 100% | 25 | 29 | 33 | dB |
| Signal strength indication output | V ₁₇₋₀ | V _{IN} = 0 dBμ, R ₁₆ = 10 kΩ, pin 17 | 0 | 0.1 | 0.4 | V |
| | V ₁₇₋₅₀ | V _{IN} = 50 dBμ, R ₁₆ = 10 kΩ, pin 17 | 1.4 | 2.3 | 3.2 | V |
| | V ₁₇₋₇₀ | V _{IN} = 70 dBμ, R ₁₆ = 10 kΩ, pin 17 | 2.5 | 4.5 | 5.5 | V |
| | V ₁₇₋₁₀₀ | V _{IN} = 100 dBμ, R ₁₆ = 10 kΩ, pin 17 | 5.0 | 5.5 | 6.0 | V |
| Muting drive output | V ₁₆₋₀ | V _{IN} = 0 dBμ, pin 16 | 4.0 | 4.8 | 5.5 | V |
| | V ₁₆₋₁₀₀ | V _{IN} = 100 dBμ, pin 16 | 0 | 0 | 0.3 | V |
| AM rejection ratio | AMR | V _{IN} = 100 dBμ, 1 kHz tone, 30% AM | 57 | 70 | | dB |
| Offset voltage | V ₈₋₁₂ | V _{IN} = 0 dBμ, pin 8 to 12 | -0.25 | 0 | +0.25 | V |
| | V ₉₋₁₂ | V _{IN} = 0 dBμ, pin 9 to 12 | -0.5 | 0 | +0.5 | V |
| SD sensitivity | V _{SD} | Pin 19 | 50 | 58 | 66 | dBμ |
| IF count output level | V _{IF-On} | V _{IN} = 100 dBμ, pin 14, C _L = 10 pF | 110 | 180 | 280 | mVrms |
| | V _{IF-OFF} | V _{IN} = 100 dBμ, pin 14, C _L = 10 pF | | 1 | 3 | mVrms |



LA1145, 1145M

Sample Application Circuit



LS1140 and LS1145 Compared

| Parameter | LA1140 | LA1145 | Remarks |
|---------------------------------|---------------------|-------------------|---|
| Package | SIP-16 | SIP-18Z MFP-20 | |
| IF amp, limiter | Direct-coupled | C-coupled | |
| Quadrature detector | ○ | ○ | |
| AF preamp | ○ | ○ | |
| AFC output | ○ | ○ | |
| Signal meter output | ○ | ⊙ | Improved linearity, variable S-meter gradient |
| Band muting | ○ | ⊙ | Improved temperature stability, V_{BE} dependent |
| IF count buffer output | – | ○ | Common with STRQ |
| SD circuit | – | ○ | For the LA1140, Coupled with the soft muting function. |
| S/N | 78 dB μ | 86 dB | |
| 3 dB μ limiting sensitivity | 25 dB μ (fixed) | 25 to 40 dB μ | –3 dB μ limiting sensitivity variable, independent of soft muting function |
| Weak signal noise output | ○ | ⊙ | |

LA1145, 1145M

LA1145 Pin Description and Typical Voltages

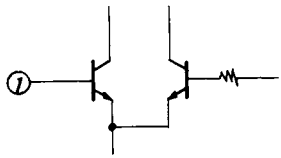
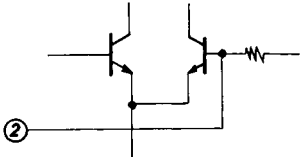




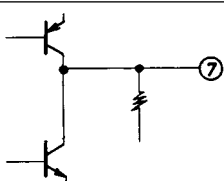
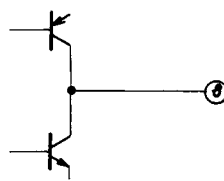
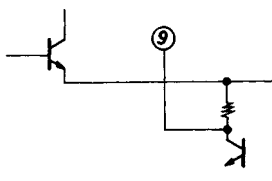
| Pin No. | Typical Voltage (V) | Description | Remarks |
|---------|---------------------|----------------------------|----------------|
| 1 | 2.6 | IF input | |
| 2 | 2.6 | IF amp bias | |
| 3 | 0.0 | IF amp GND | |
| 4 | 4.0 | Mute start control | |
| 5 | 0.2 | Mute gradient control | |
| 6 | 2.1 | Mute attenuation control | |
| 7 | 4.9 | AF output | |
| 8 | 5.0 | AFC output | |
| 9 | 4.8 | IF output | |
| 10 | 4.8 | Quadrature detection input | |
| 11 | 4.8 | Voltage regulator output | |
| 12 | 8.0 | V _{CC} | |
| 13 | 0.1 | IF count output, control | |
| 14 | 0.0 | GND for detection circuit | |
| 15 | 4.8 | Mute driver | |
| 16 | 0.2 | S-meter output | |
| 17 | 0.2 | SD sensitivity control | |
| 18 | 0.1 | SD output | Open collector |

LA1145M Pin Description and Typical Voltages

| Pin No. | Typical Voltage (V) | Description | Remarks |
|---------|---------------------|----------------------------|----------------|
| 1 | – | NC | |
| 2 | 2.6 | IF input | |
| 3 | 2.6 | IF amp bias | |
| 4 | 0.0 | IF amp GND | |
| 5 | 4.0 | Mute start control | |
| 6 | 0.2 | Mute gradient control | |
| 7 | 2.1 | Mute attenuation control | |
| 8 | 4.9 | AF output | |
| 9 | 5.0 | AFC output | |
| 10 | 4.8 | IF output | |
| 11 | 4.8 | Quadrature detection input | |
| 12 | 4.8 | Voltage regulator output | |
| 13 | 8.0 | V _{CC} | |
| 14 | 0.1 | IF count output, control | |
| 15 | 0.0 | GND for detection circuit | |
| 16 | 4.8 | Mute driver | |
| 17 | 0.2 | S-meter output | |
| 18 | 0.2 | SD sensitivity control | |
| 19 | 0.1 | SD output | Open collector |
| 20 | – | NC | |

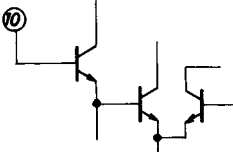
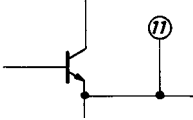
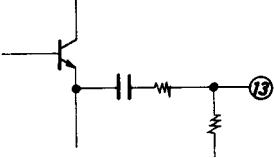

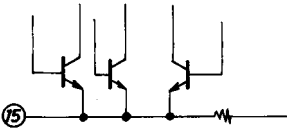
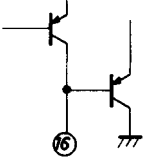
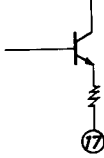
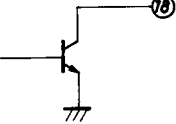
LA1145, 1145M

LA1145 Pin Functions (1)

| Pin No. | Function | Internal Equivalent Circuit | Notes |
|---------|----------------------------------|---|--|
| 1 | IF input |  | |
| 2 | Bias pin |  | |
| 3 | GND |  | IF limiting amp GND |
| 4 | Soft mute start point control |  | For setting the soft mute starting point. |
| 5 | Soft muting gradient control pin |  | Can be used for S-meter output. For setting the mute gradient from the soft mute starting point to the noise finishing point. |
| 6 | Mute Att |  | For setting amount of mute attenuation. The demodulation level changes when the external resistance value is varied. |
| 7 | FM-AF output |  | |
| 8 | AFC input |  | |
| 9 | IF output |  | Output to the phase circuit |

LA1145, 1145M

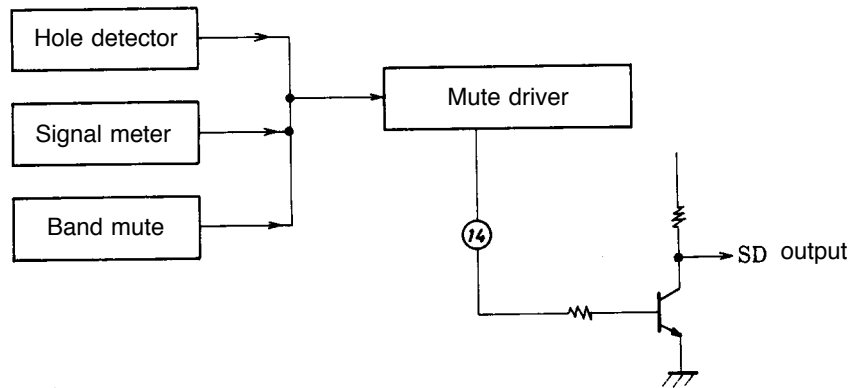
LA1145 Pin Functions (2)

| Pin No. | Function | Internal Equivalent Circuit | Notes |
|---------|------------------------|---|--|
| 10 | IF input |  | IF input via the phase shift circuit. The mute circuit malfunctions and demodulation output decreases if the voltage level at this pin drops below 180 mV. |
| 11 | Vref |  | 4.8 V |
| 12 | V _{CC} | | Supply voltage 7.5 to 14 V |
| 13 | IF buffer output |  | |
| 14 | GND |  | FM detection circuit GND |
| 15 | Mute driver |  | Amount of mute attenuation depends on and is controlled by the voltage at this pin. |
| 16 | S-meter output |  | PNP open collector output |
| 17 | SD sensitivity setting |  | Can be used for S-meter output |
| 18 | SD output |  | High active |

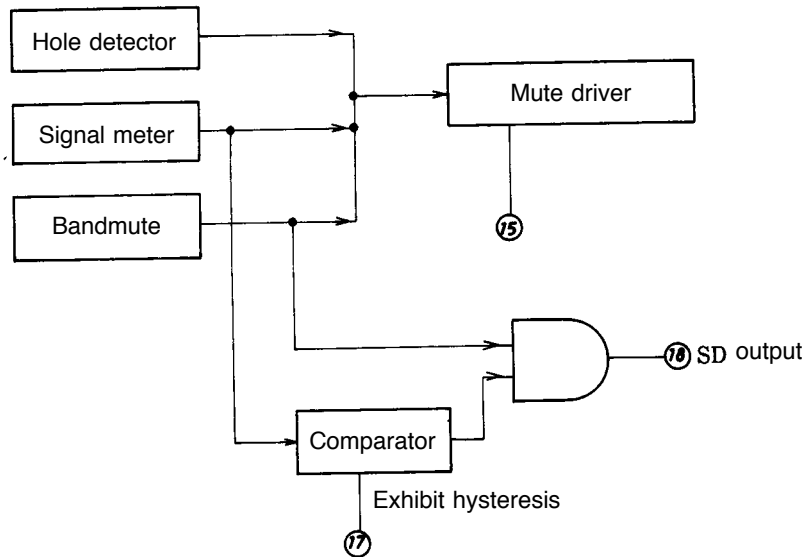
SD Output Circuit

1. LA1145 SD output differs from the LA1140's pin substitute SD output as shown below. The SD output on the LA1145 does not operate in conjunction with the soft mute characteristics.

1) LA1140



2) LA1145



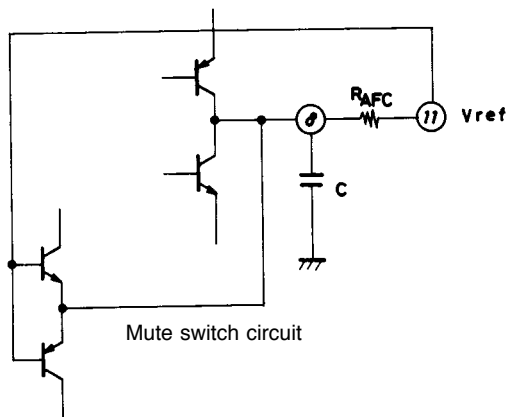
As shown, the SD output is the logical AND of the band mute and S-meter comparator outputs.

2. Signal search using the SD output circuit

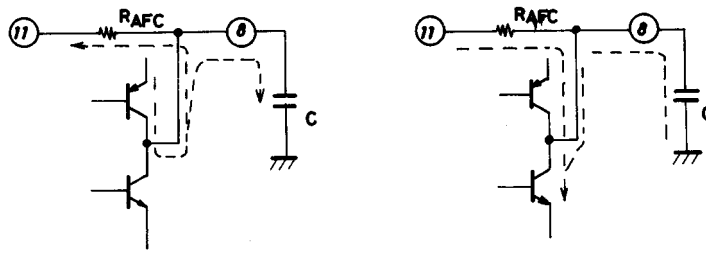
2-1 The transition response characteristics of the SD output circuit depends on the time constants of pins 15, 16, 17 and 8. As the SD output transition response characteristics are determined by the pin with the largest time constant, erroneous stopping will result when a search time is less than the largest one.

2-2 Band mute range circuit time constant (pin 8)

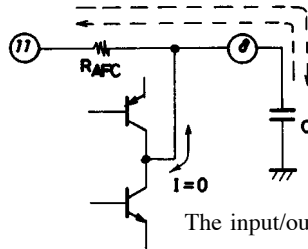
An equivalent circuit to the band circuit is shown below.



1) Current path during detuning



2) Current return path from detuning

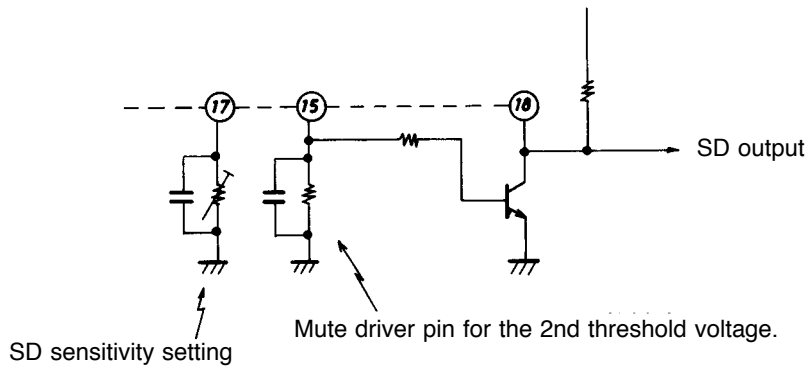


The input/output current from pin 8 becomes zero during return.

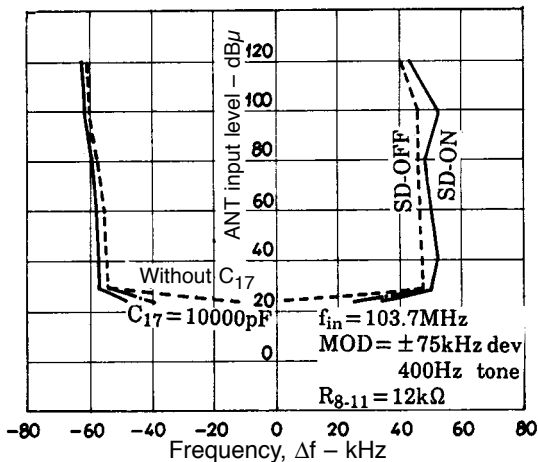
As can be seen from the above circuit diagrams, the time constant during detuning is determined by the internal PNP resistance, the NPN collector resistance and the capacitance of the externally- mounted capacitor. This time constant is determined by the external resistance R_{AFC} and capacitor C . This time constant, $\tau = R_{AFC} \times C$, must be set depending on the required search time.

3. Narrow-band SD output circuit

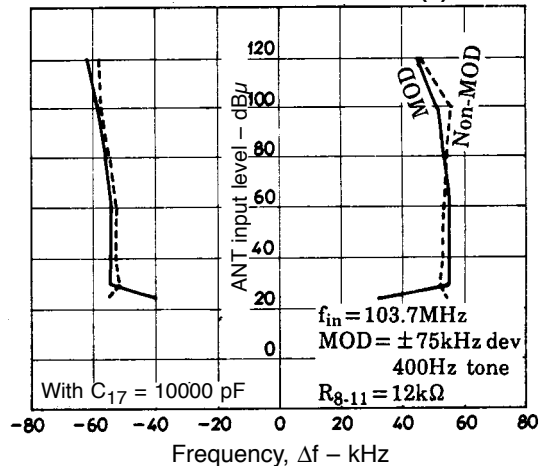
An IF count circuit is provided for equipment compatibility for the European marketplace. However, if the band is made narrow using only the SD circuit, there is a tendency for the number of erroneous stops caused by an undesired signal to increase. To prevent this, two threshold voltages should be used to control the SD circuit.



Band Mute Characteristics (1)



Band Mute Characteristics (2)



Soft Mute Characteristics

1. Control

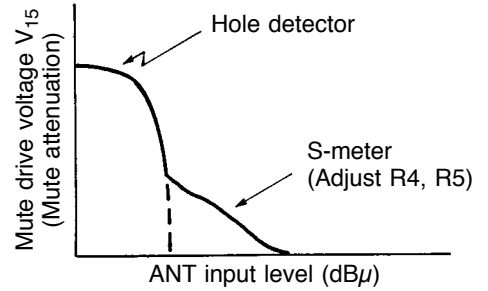
The S/N setting (C/N) for weak inputs and the -3 dB limiting sensitivity can be controlled by obtaining the proper value for the un-soft muted input/output signal characteristic. However, usable sensitivity cannot be controlled as this is determined by the front end and IF design which are unrelated to soft muting.

2. Soft mute setting

Soft mute operation depends on the S-meter circuit voltage and the hole detector circuit voltage. As shown in the graph on the right, the degree of soft muting correlates with the mute drive voltage, V15. The control signal line of the mute drive voltage switches before and after the 10 dBμ ANT divergence point.

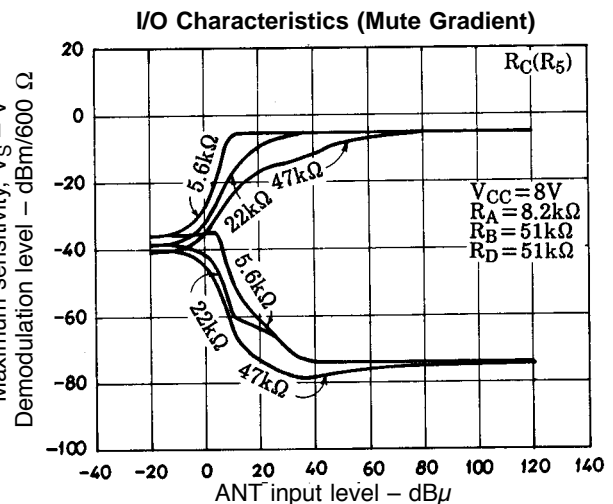
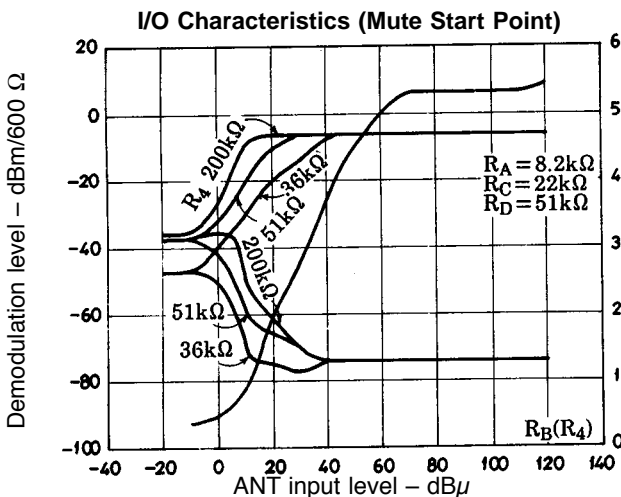
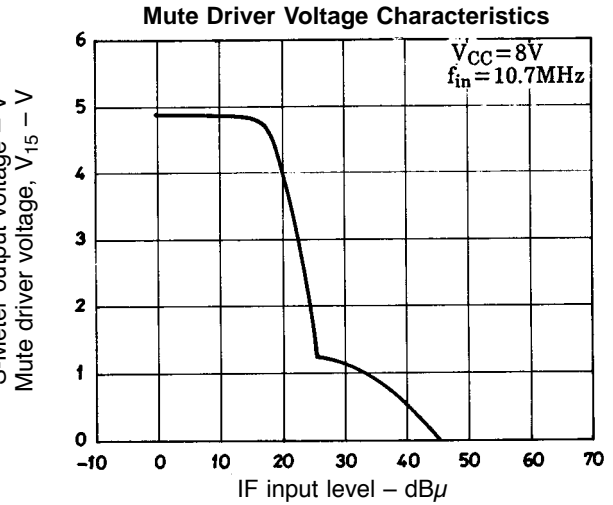
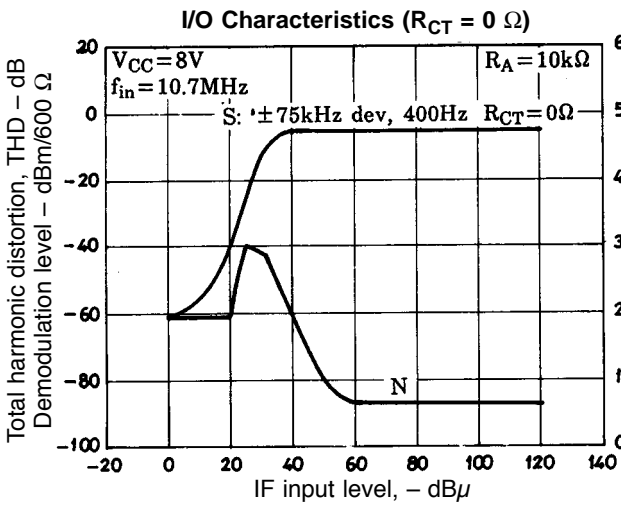
When adjusting the soft mute with a weak signal which does not affect the S-meter, first adjust it using the hole detector input signal. However, as the S-meter output will readjust the soft mute level, also adjust the soft mute using the S-meter output. At this point, the hole detector output adjusts the gain up to the IF input, causing a variance. Also, the S-meter output is varied by the value of R16.

The LA1145 differs from the LA1140 in that it works with the internal soft mute circuit continuously engaged.

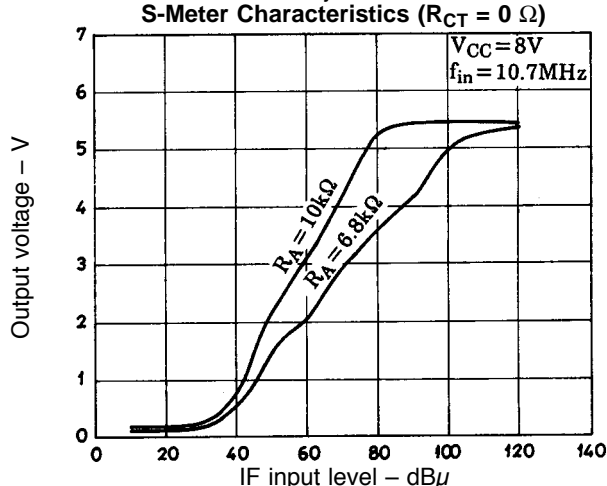
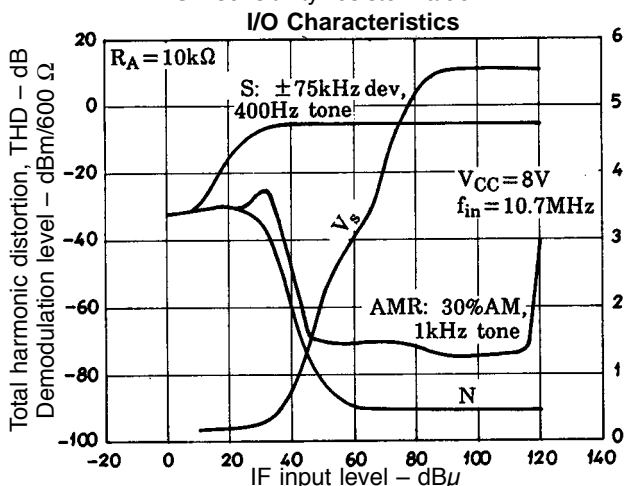
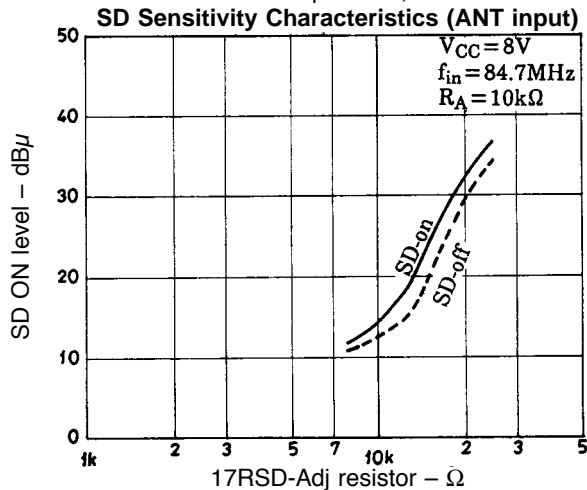
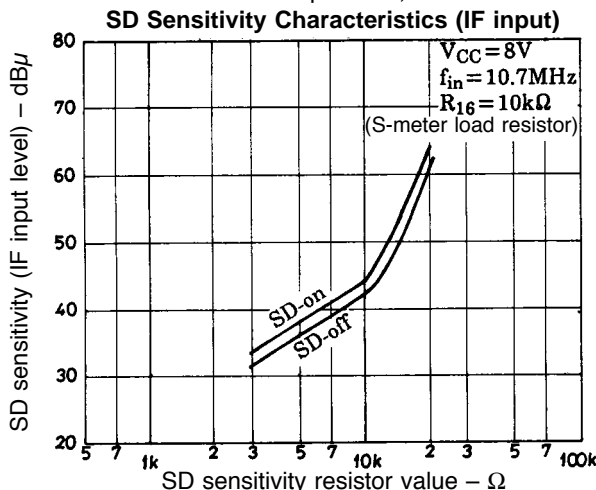
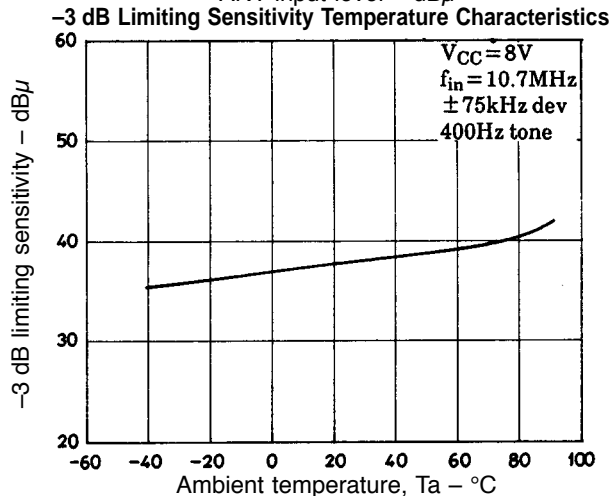
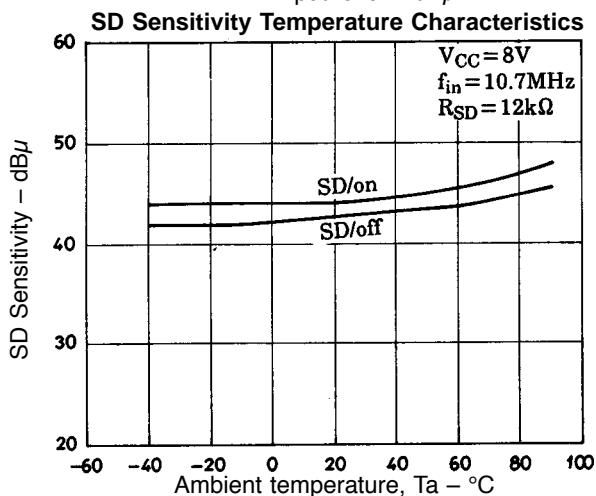
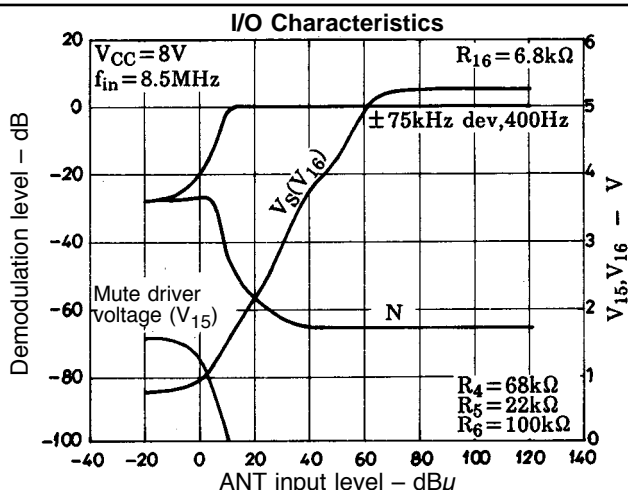
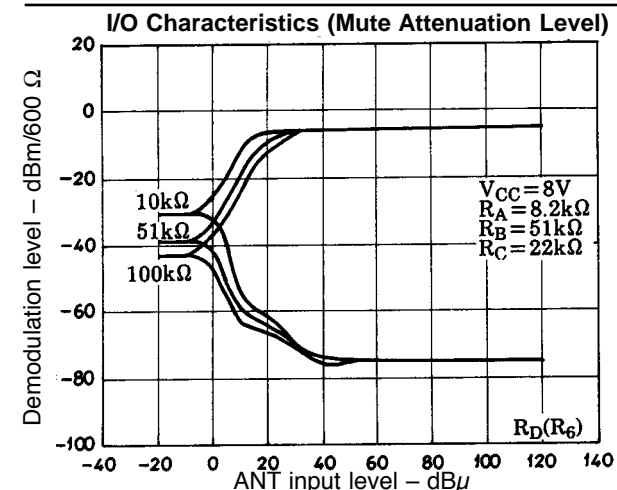


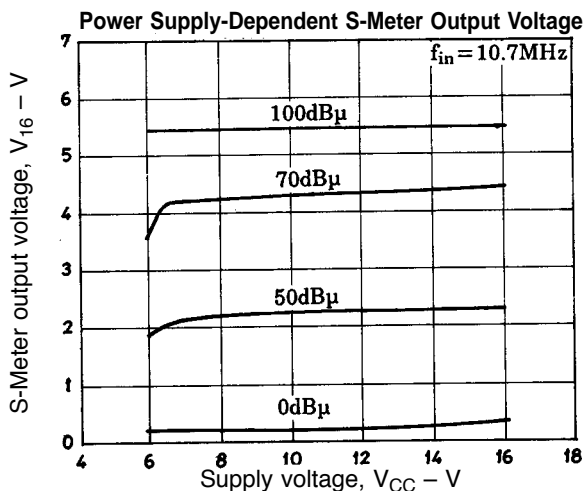
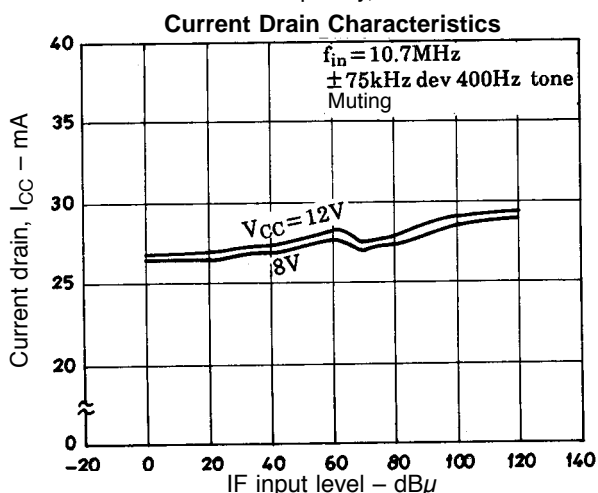
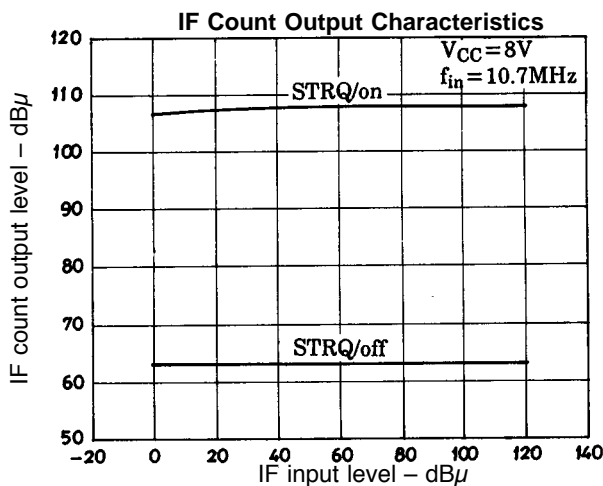
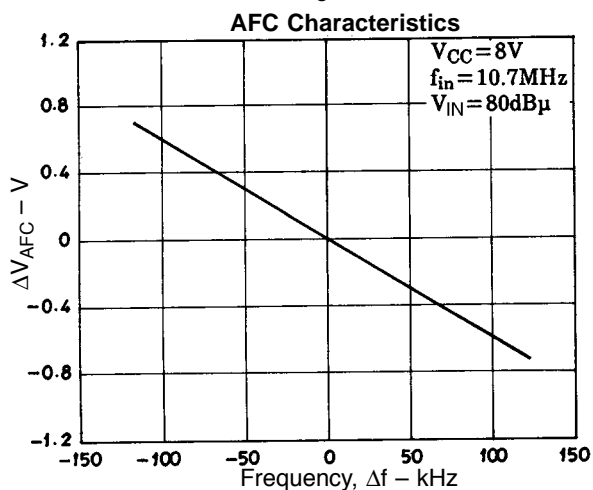
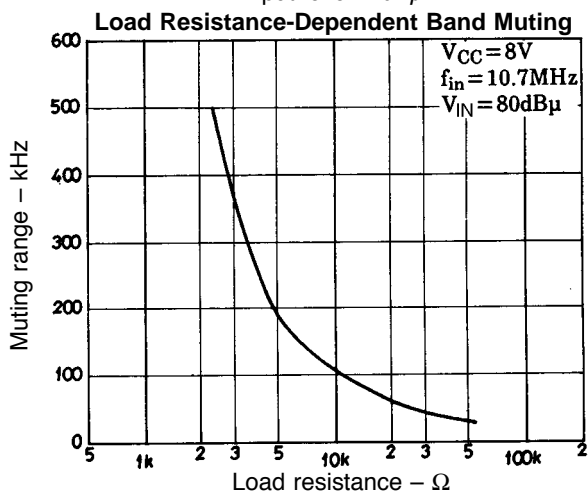
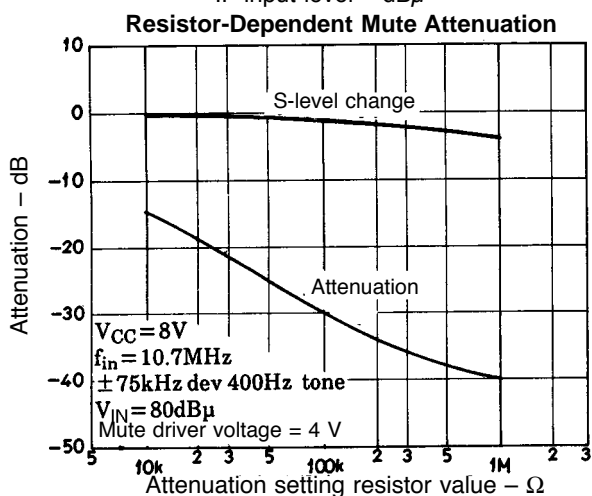
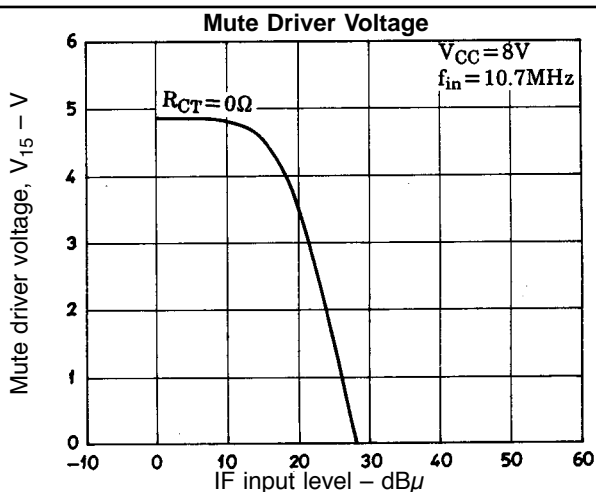
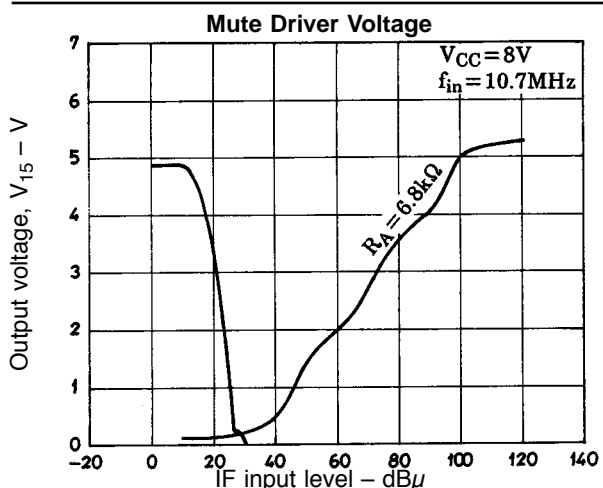
3. Soft mute transition response characteristic

The degree of soft muting automatically varies according to the change in input field strength. Omitting the influence of the front end wideband AGC circuit, the LA1145's response speed is dependent on the time constant at pins 15 and 16.

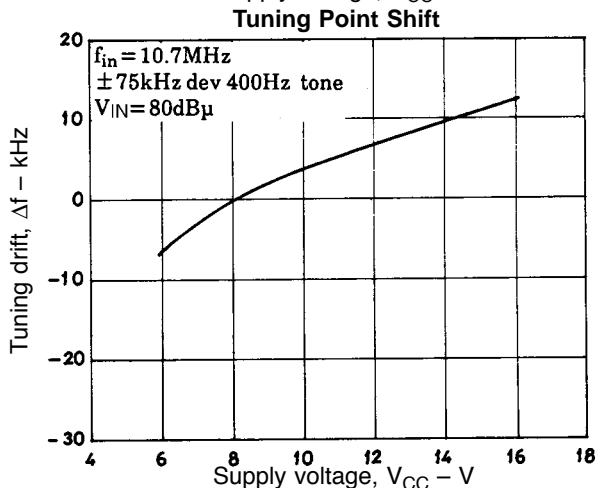
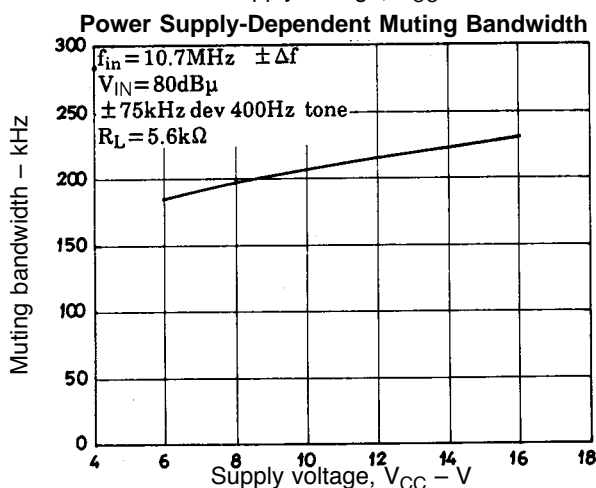
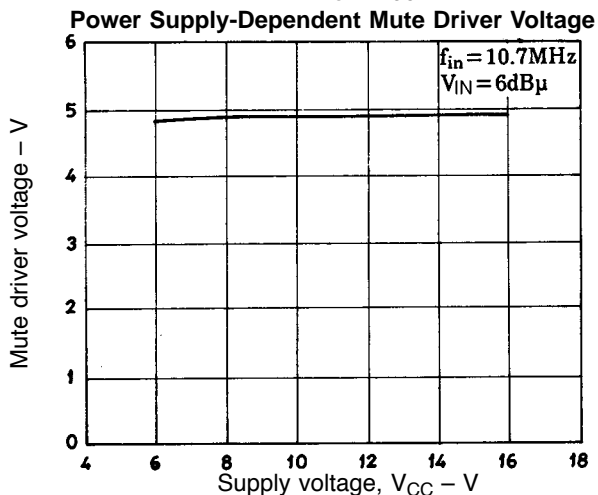
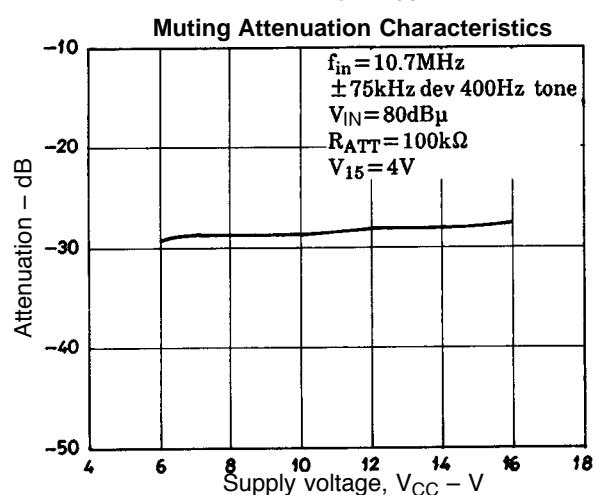
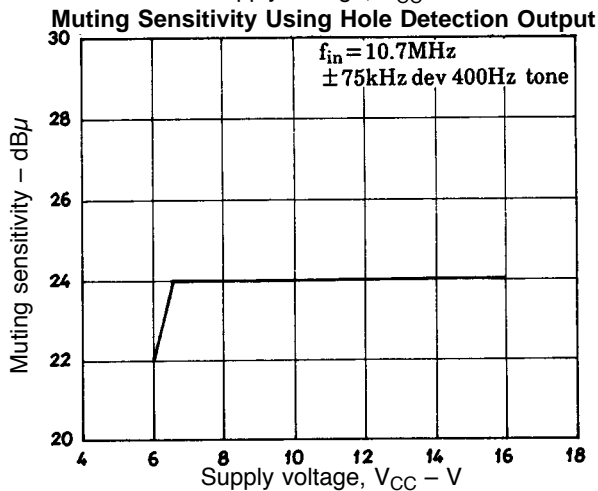
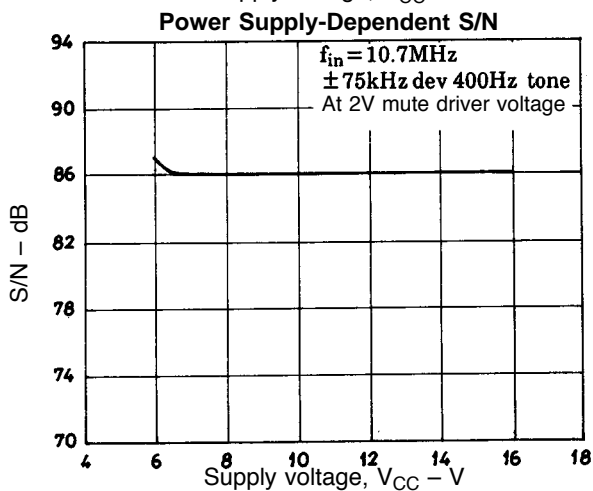
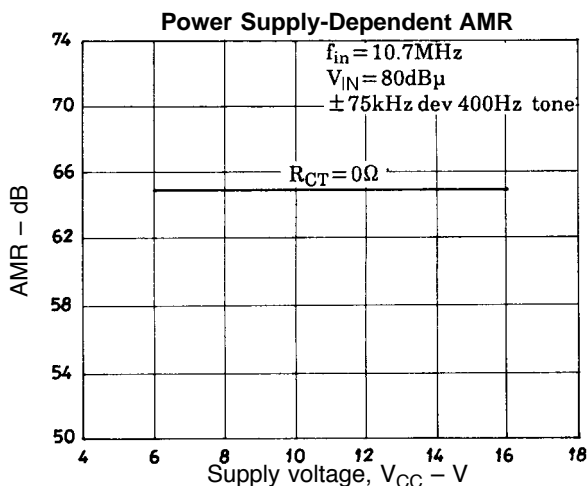
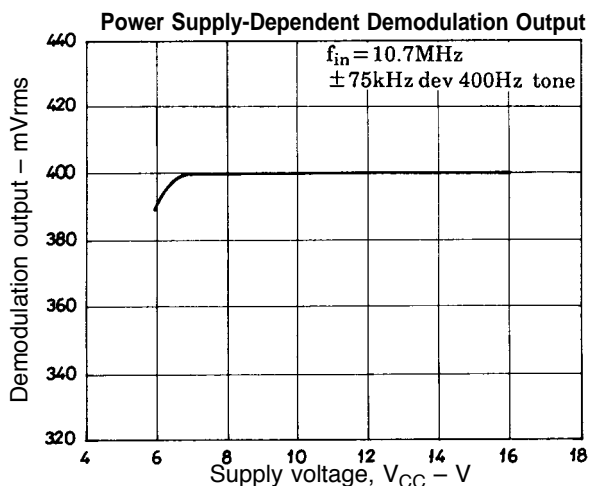


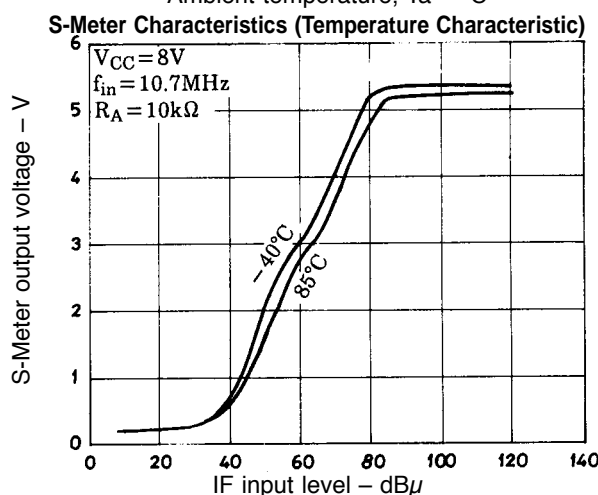
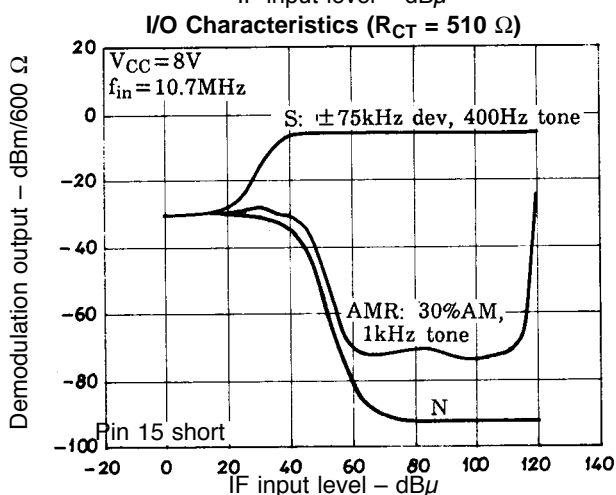
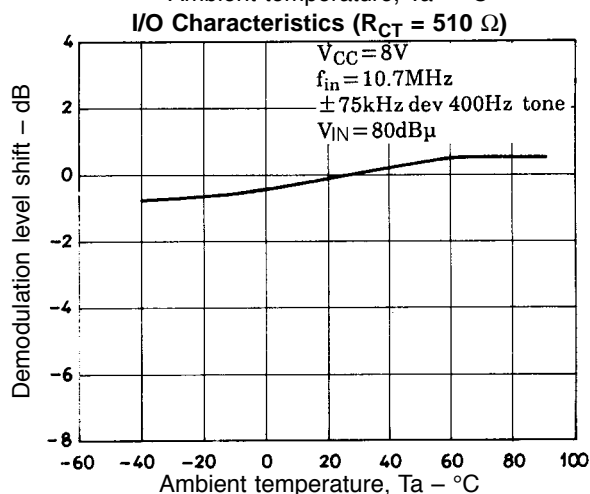
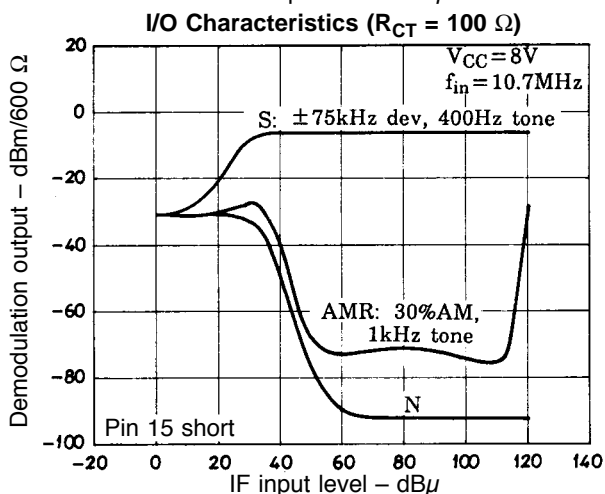
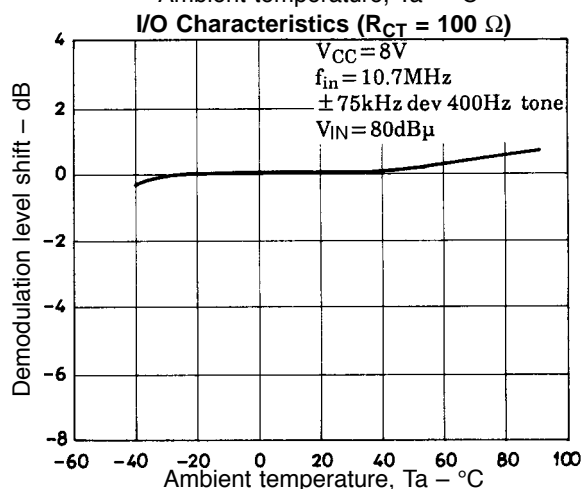
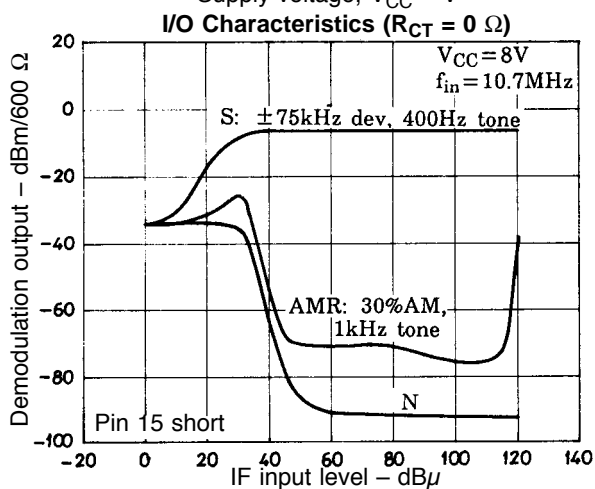
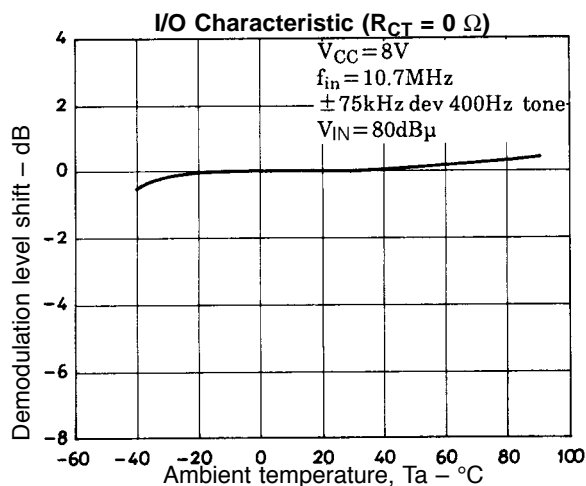
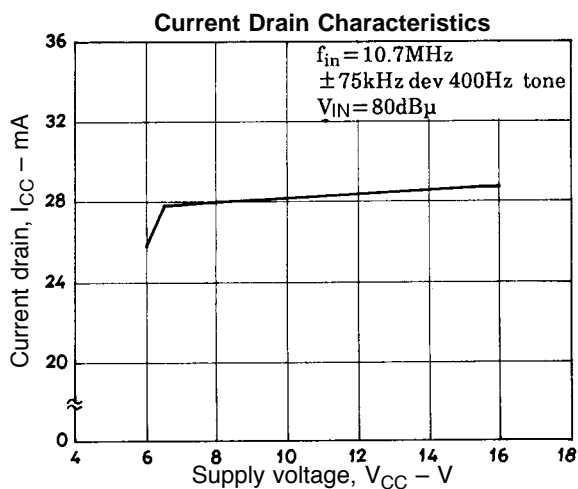
LA1145, 1145M



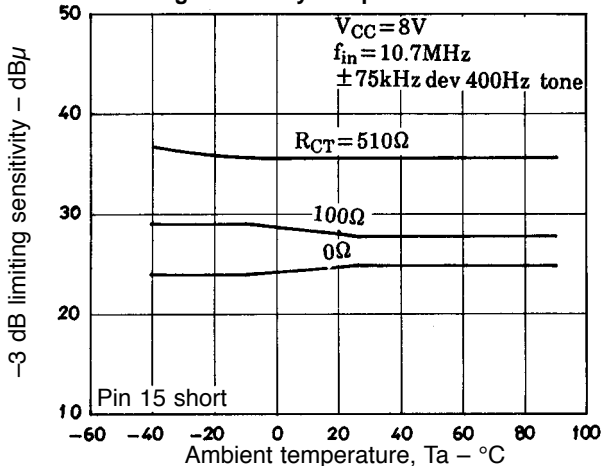


LA1145, 1145M

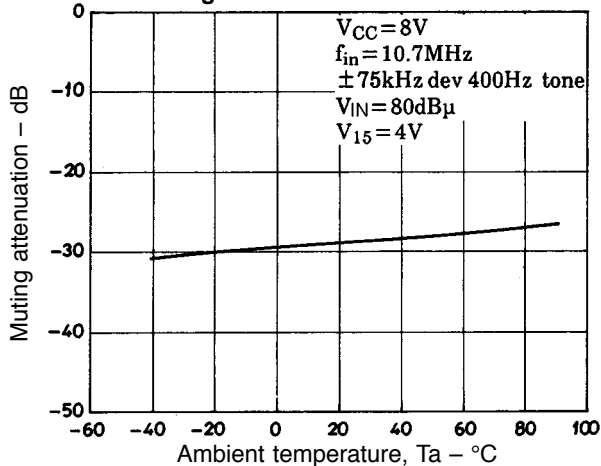




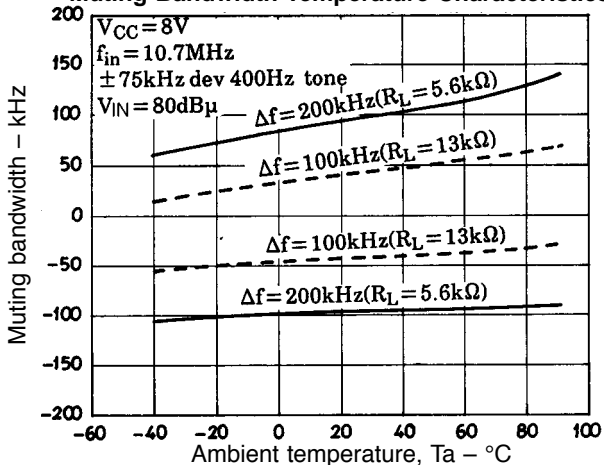
-3 dB Limiting Sensitivity Temperature Characteristics



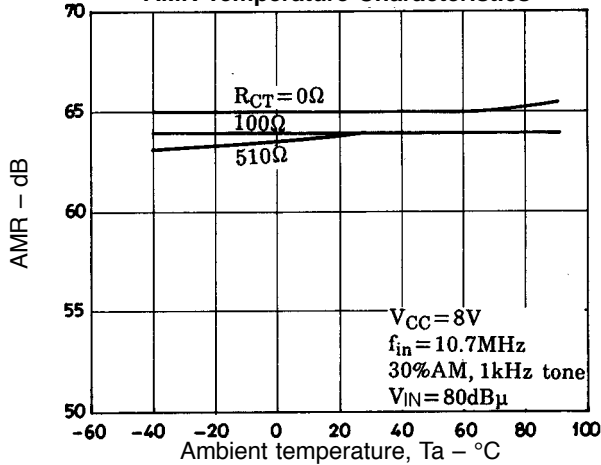
Muting Attenuation Characteristics



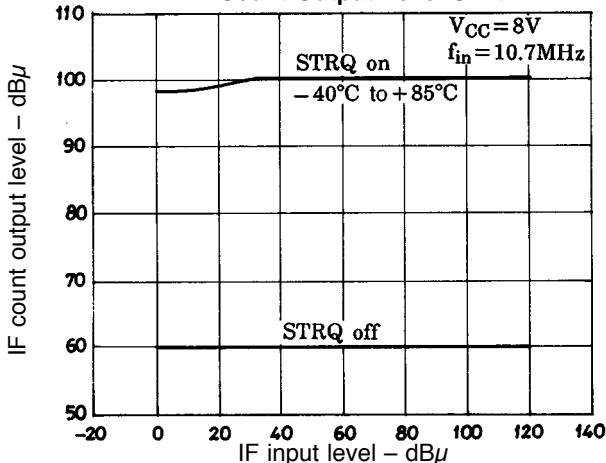
Muting Bandwidth Temperature Characteristics



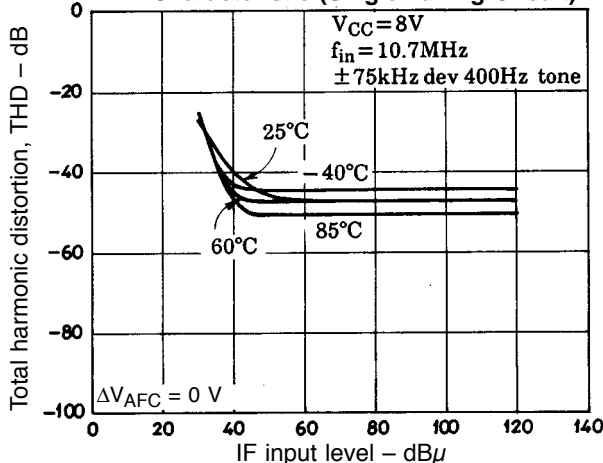
AMR Temperature Characteristics



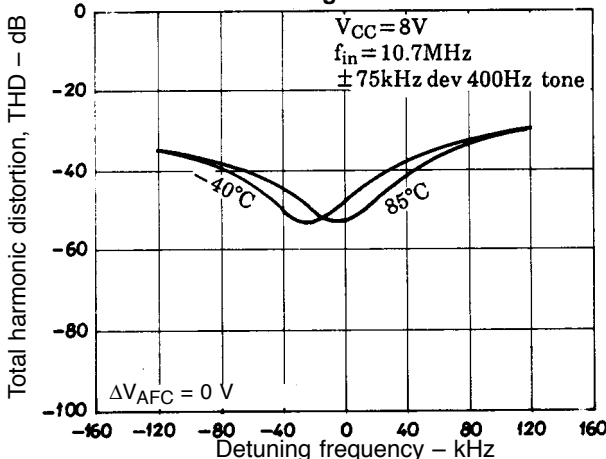
IF Count Output Level Shift



THD Characteristic (Single Tuning Circuit)





THD Detuning Characteristics



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